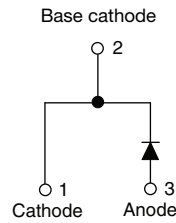


Hyperfast Rectifier, 8 A FRED Pt[®] G5



FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	8 A
V_R	1200 V
V_F at I_F at 125 °C	1.8 V
t_{rr}	33 ns
T_J max.	175 °C
Package	TO-220AC 2L
Circuit configuration	Single

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	V_{RRM}		1200	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 122\text{ °C}, D = 0.50$	8	A
Repetitive peak forward current	I_{FRM}	$T_C = 122\text{ °C}, D = 0.50, f = 20\text{ kHz}$	16	
Non-repetitive peak surge current	I_{FSM}	$T_C = 45\text{ °C}, t_p = 10\text{ ms}, \text{ sine wave}$	65	
Operating junction and storage temperature	T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	1200	-	-	V
Forward voltage	V_F	$I_F = 8\text{ A}$	-	1.9	2.5	
		$I_F = 8\text{ A}, T_J = 125\text{ °C}$	-	1.8	-	
Reverse leakage current	I_R	$V_R = V_R \text{ rated}$	-	-	50	μA
		$T_J = 125\text{ °C}, V_R = V_R \text{ rated}$	-	-	500	
Junction capacitance	C_T	$V_R = 200\text{ V}$	-	5	-	pF
Series inductance	L_S	Measured to lead 5 mm from package body	-	8	-	nH



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	t_{rr}	$I_F = 1.0\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	33	55	ns	
		$T_J = 25\text{ }^\circ\text{C}$	-	100	-		
		$T_J = 125\text{ }^\circ\text{C}$	-	165	-		
Peak recovery current	I_{RRM}	$I_F = 6\text{ A}$ $di_F/dt = 400\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	8.0	-	A
			$T_J = 125\text{ }^\circ\text{C}$	-	10	-	
Reverse recovery charge	Q_{rr}	$I_F = 6\text{ A}$ $di_F/dt = 400\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	300	-	nC
			$T_J = 125\text{ }^\circ\text{C}$	-	700	-	
Reverse recovery time	t_{rr}	$I_F = 8\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 800\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	60	-	ns
			$T_J = 125\text{ }^\circ\text{C}$	-	80	-	
Peak recovery current	I_{RRM}	$I_F = 8\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 800\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	16	-	A
			$T_J = 125\text{ }^\circ\text{C}$	-	26	-	
Reverse recovery charge	Q_{rr}	$I_F = 8\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 800\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	570	-	nC
			$T_J = 125\text{ }^\circ\text{C}$	-	1350	-	

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R_{thJC}		-	-	2.3	$^\circ\text{C}/\text{W}$
Weight			-	2	-	g
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	175	$^\circ\text{C}$
Marking device		Case style TO-220AC 2L	E5TH0812			

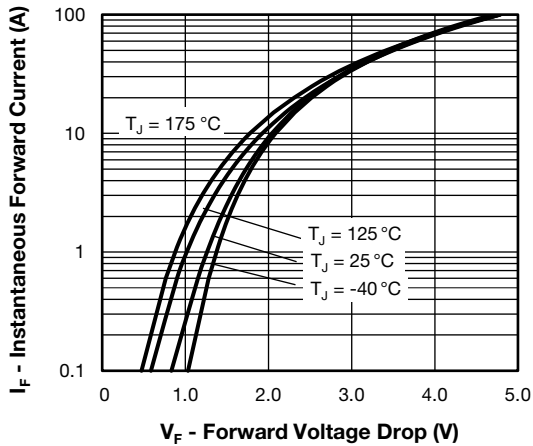


Fig. 1 - Forward Voltage Drop Characteristics

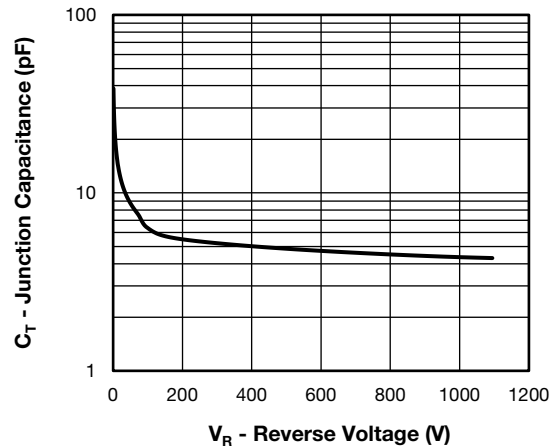


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

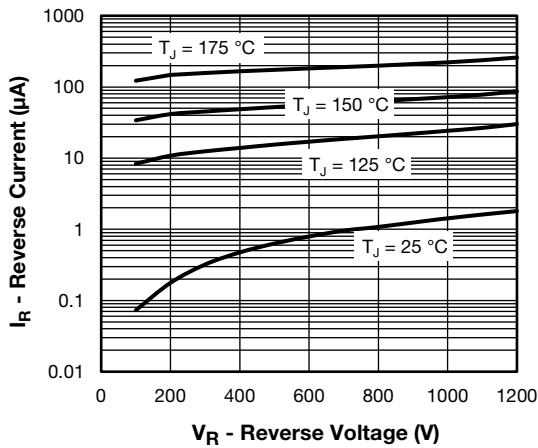


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

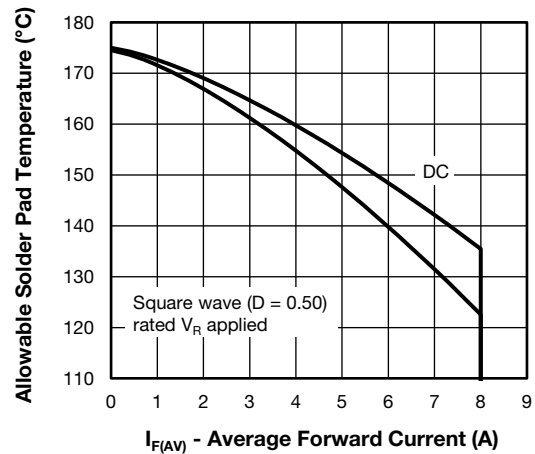


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

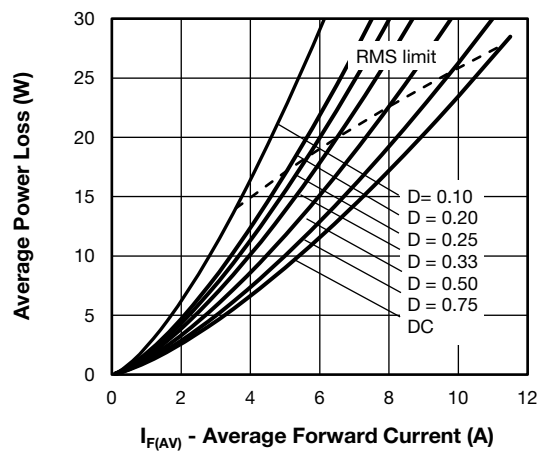


Fig. 5 - Forward Power Loss Characteristics

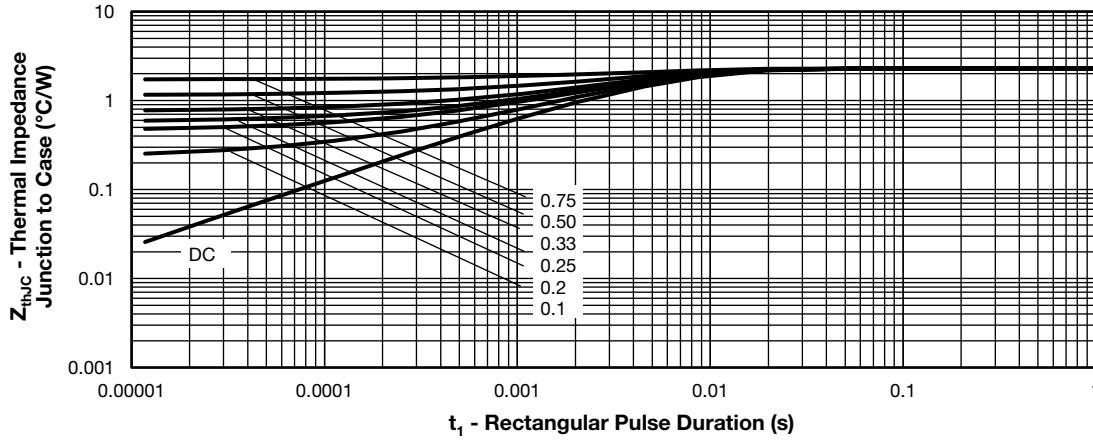


Fig. 6 - Transient Thermal Impedance, Junction to Case

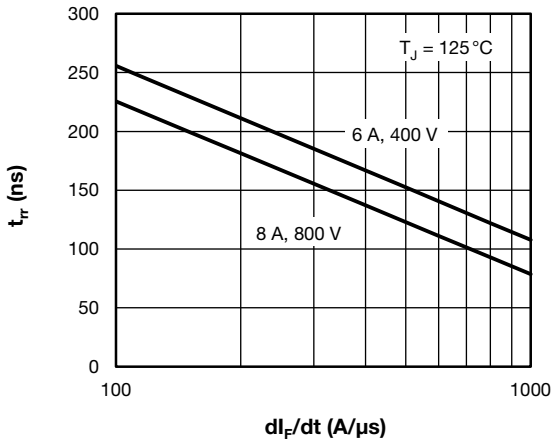


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

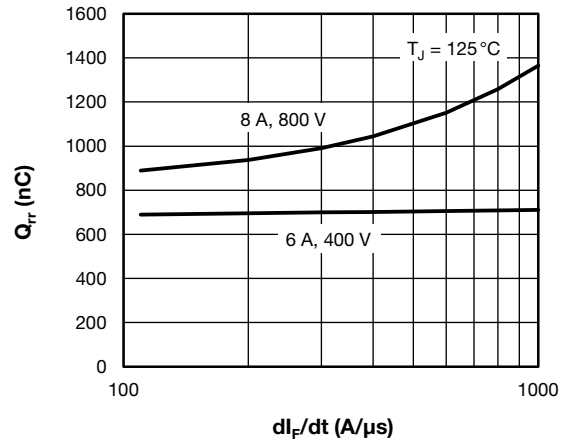


Fig. 8 - Typical Stored Charge vs. dI_F/dt

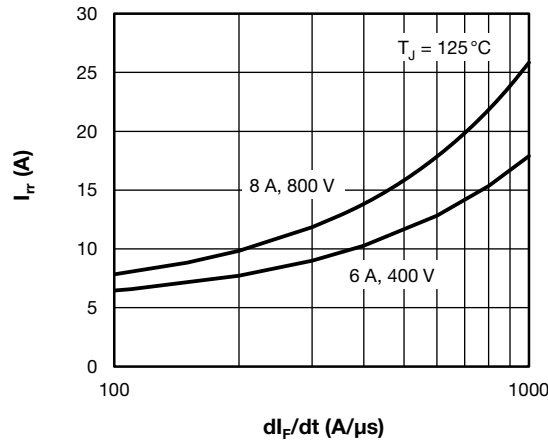


Fig. 9 - Typical Recovery Current vs. dI_F/dt

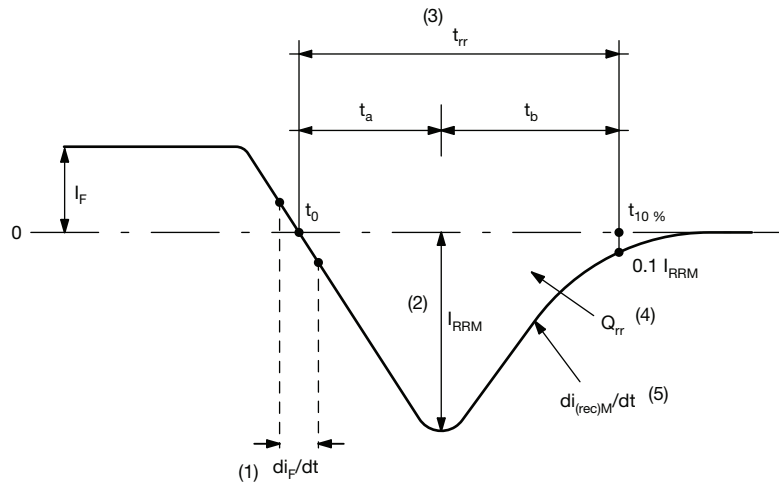


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, $0.1 I_{RRM}$
- (4) Q_{rr} - area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

- (5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	E	5	T	H	08	12	-M3
	①	②	③	④	⑤	⑥	⑦	⑧

- | | |
|---|--|
| 1 | - Vishay Semiconductors product |
| 2 | - E = single diode |
| 3 | - 5 = FRED generation 5 |
| 4 | - Package:
T = TO-220AC 2L |
| 5 | - H = hyperfast recovery |
| 6 | - Current rating (08 = 8 A) |
| 7 | - Voltage rating (12 = 1200 V) |
| 8 | - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free |

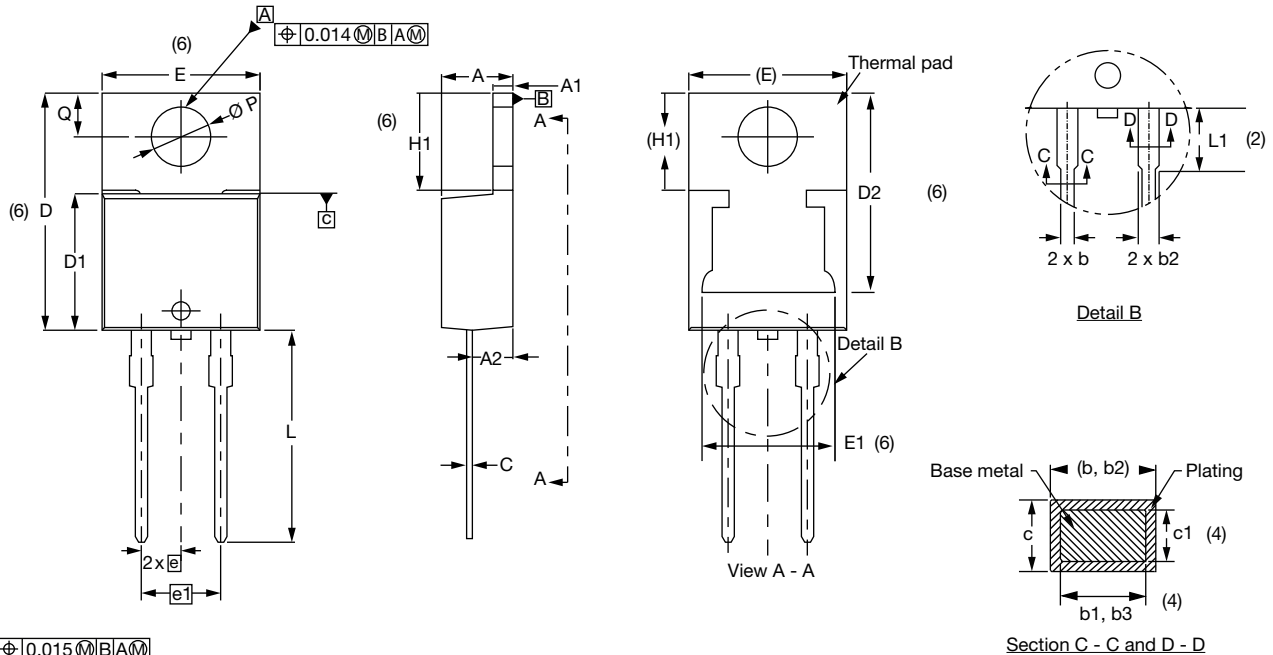
ORDERING INFORMATION (Example)		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-E5TH0812-M3	50	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96156
Part marking information	www.vishay.com/doc?95391



TO-220AC 2L

DIMENSIONS in millimeters and inches



Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055		E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		e	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4	e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068		H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4	L	13.52	14.02	0.532	0.552	
c	0.36	0.61	0.014	0.024		L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4	∅ P	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3	Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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